

RRR030P03FRA

Pch 30V 3A Power MOSFET

| V_{DSS} | -30V |
|--------------------|---------|
| $R_{DS(on)}(Max.)$ | 75m $Ω$ |
| I _D | -3A |
| P_D | 1.0W |

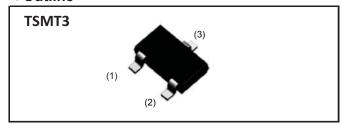
Features

- 1) Low on resistance.
- 2) Built-in G-S Protection Diode.
- 3) Small Surface Mount Package (TSMT3).
- 4) Pb-free lead plating; RoHS compliant
- 5) AEC-Q101 Qualified

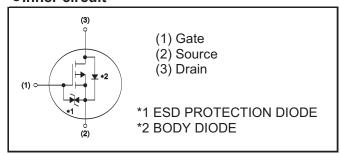
Application

DC/DC converters

Outline



•Inner circuit



Packaging specifications

| | Packaging | Taping |
|------|---------------------------|--------|
| | Reel size (mm) | 180 |
| Type | Tape width (mm) | 8 |
| Туре | Basic ordering unit (pcs) | 3,000 |
| | Taping code | TL |
| | Marking | UA |

● Absolute maximum ratings(T_a = 25°C)

| Parameter | Symbol | Value | Unit |
|------------------------------|-------------------------|-------------|------|
| Drain - Source voltage | $V_{	extsf{DSS}}$ | -30 | V |
| Continuous drain current | I _D *1 | ±3 | А |
| Pulsed drain current | I _{D,pulse} *2 | ±12 | А |
| Gate - Source voltage | V_{GSS} | ±20 | V |
| Dower discination | P _D *3 | 1.0 | W |
| Power dissipation | P _D *4 | 0.54 | W |
| Junction temperature | T _j | 150 | °C |
| Range of storage temperature | T _{stg} | -55 to +150 | °C |

●Thermal resistance

| Parameter | Symbol | Values | | | Unit |
|--|----------------------|--------|------|------|-------|
| rarameter | Symbol | Min. | Тур. | Max. | Offic |
| Thermal resistance, junction - ambient | R _{thJA} *3 | - | - | 125 | °C/W |
| Thermal resistance, junction - ambient | R _{thJA} *4 | - | - | 231 | °C/W |

•Electrical characteristics($T_a = 25$ °C)

| Parameter | Symbol | Conditions | Values | | | Unit | |
|--|---|--|--------|------|------|-------|--|
| Parameter Symbol | | Conditions | Min. | Тур. | Max. | Offic | |
| Drain - Source breakdown voltage | V _{(BR)DSS} | $V_{GS} = 0V$, $I_D = -1mA$ | -30 | - | - | V | |
| Breakdown voltage temperature coefficient | $\frac{\Delta V_{(BR)DSS}}{\Delta T_{j}}$ | I _D = -1mA referenced to 25°C | 1 | -25 | , | mV/°C | |
| Zero gate voltage drain current | I _{DSS} | $V_{DS} = -30V, V_{GS} = 0V$ | - | - | -1 | μА | |
| Gate - Source leakage current | I _{GSS} | $V_{GS} = \pm 20V, V_{DS} = 0V$ | ı | - | ±10 | μА | |
| Gate threshold voltage | V _{GS (th)} | $V_{DS} = -10V, I_{D} = -1mA$ | -1 | - | -2.5 | V | |
| Gate threshold voltage temperature coefficient | $\frac{\Delta V_{(GS)th}}{\Delta T_{j}}$ | I _D = -1mA referenced to 25°C | - | 3.9 | - | mV/°C | |
| | | $V_{GS} = -10V, I_D = -3A$ | - | 55 | 75 | | |
| Static drain - source | D *5 | $V_{GS} = -4.5V, I_D = -1.5A$ | - | 85 | 115 | | |
| on - state resistance | $R_{DS(on)}$ | $V_{GS} = -4.0V, I_D = -1.5A$ | - | 95 | 125 | mΩ | |
| | | $V_{GS} = -10V$, $I_D = -3A$, $T_j = 125$ °C | - | 85 | 120 | | |
| Gate input resistannce | R_G | f = 1MHz, open drain | - | 25 | - | Ω | |
| Transconductance | 9 fs *5 | $V_{DS} = -10V, I_{D} = -3A$ | - | 5 | - | S | |

^{*1} Limited only by maximum temperature allowed.

^{*2} Pw $\leq 10 \mu s, \, Duty \, cycle \leq 1\%$

^{*3} Mounted on a ceramic boad (30×30×0.8mm)

^{*4} Mounted on a FR4 (12×20×0.8mm)

●Electrical characteristics(T_a = 25°C)

| Parameter | Symbol | Conditions | Values | | | Unit |
|------------------------------|------------------------|-------------------------------------|--------|------|------|-------|
| Parameter | Symbol | Conditions | Min. | Тур. | Max. | Offic |
| Input capacitance | C _{iss} | V _{GS} = 0V | - | 480 | - | |
| Output capacitance | C _{oss} | V _{DS} = -10V | - | 70 | - | pF |
| Reverse transfer capacitance | C_{rss} | f = 1MHz | - | 70 | - | |
| Turn - on delay time | $t_{d(on)}^{*5}$ | $V_{DD} \simeq -15V, V_{GS} = -10V$ | - | 7 | - | |
| Rise time | t _r *5 | I _D = -1.5A | - | 18 | - | no |
| Turn - off delay time | t _{d(off)} *5 | $R_L = 10\Omega$ | - | 50 | - | ns |
| Fall time | t _f *5 | $R_G = 10\Omega$ | - | 35 | - | |

•Gate Charge characteristics($T_a = 25$ °C)

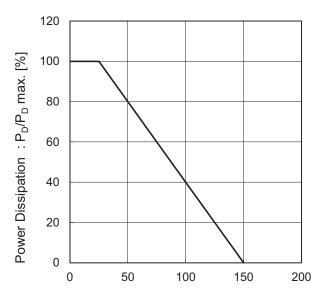
| Parameter | Symbol | Conditions | Values | | | Unit |
|----------------------|--------------------|--|--------|------|------|-------|
| - arameter | Оуппоог | Conditions | Min. | Тур. | Max. | Offic |
| Total gate charge | +- | $V_{DD} \simeq -15V$, $I_D = -3A$ $V_{GS} = -5V$ | - | 5.2 | - | |
| Total gate charge | Q _g "5 | $V_{DD} = -15V, I_D = -3A$ $V_{GS} = -10V$ | - | 11 | 22 | nC |
| Gate - Source charge | Q _{gs} *5 | $V_{DD} \simeq -15V, I_{D} = -3A$ $V_{GS} = -5V$ | - | 1.6 | - | |
| Gate - Drain charge | Q _{gd} *5 | $V_{GS} = -5V$ | - | 1.6 | - | |

●Body diode electrical characteristics (Source-Drain)(T_a = 25°C)

| Parameter | Symbol Conditions | | Values | | | Unit |
|---|--------------------|----------------------------|--------|------|------|-------|
| Parameter | Symbol | Conditions | Min. | Тур. | Max. | Offic |
| Inverse diode continuous, forward current | l _S *1 | T _a = 25°C | - | - | -0.8 | А |
| Forward voltage | V _{SD} *5 | $V_{GS} = 0V, I_s = -3.0A$ | - | - | 1.2 | V |

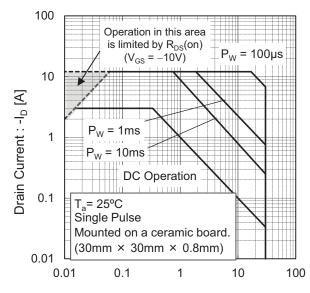
^{*5} Pulsed

Fig.1 Power Dissipation Derating Curve



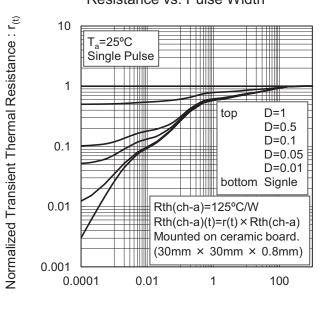
Junction Temperature : Tj [°C]

Fig.2 Maximum Safe Operating Area



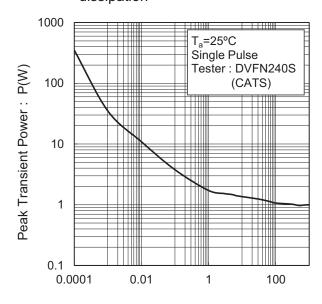
Drain - Source Voltage : -V_{DS} [V]

Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width



Pulse Width : P_W [s]

Fig.4 Single Pulse Maxmum Power dissipation



Pulse Width: P_W [s]

Fig.5 Typical Output Characteristics(I)

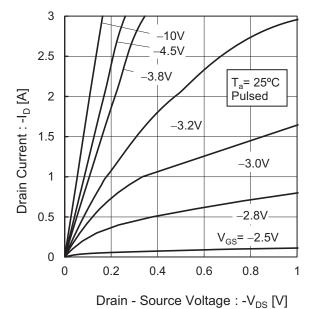
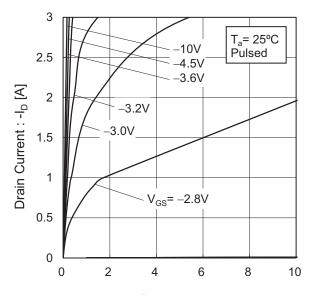


Fig.6 Typical Output Characteristics(II)



Drain - Source Voltage : -V_{DS} [V]

Fig.7 Breakdown Voltage vs. Junction Temperature Drain - Source Breakdown Voltage : V_{(BR)DSS} [V] 60 $V_{GS}=0V$ $I_D = -1mA$ pulsed 40 20 0 -50 0 50 100 150 Junction Temperature : T_i [°C]

10 $V_{DS} = -10V$ Pulsed $T_a = 125^{\circ}C$ $T_a = 75^{\circ}C$ $T_a = 25^{\circ}C$ $T_a = -25^{\circ}C$ $T_a = -25^{\circ}C$

Fig.8 Typical Transfer Characteristics

Fig.9 Gate Threshold Voltage

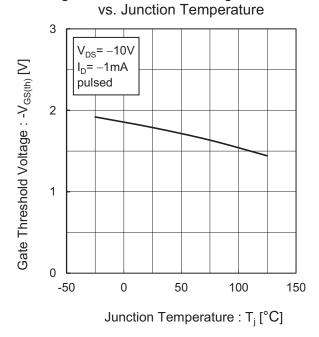
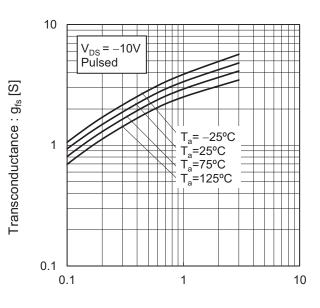


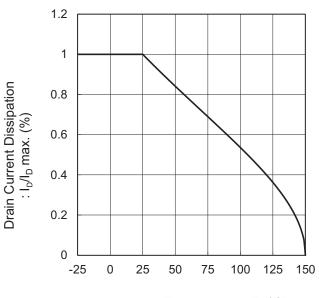
Fig.10 Transconductance vs. Drain Current

Gate - Source Voltage : V_{GS} [V]



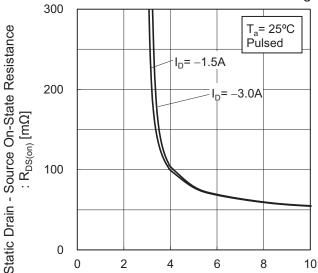
Drain Current : I_D [A]

Fig.11 Drain CurrentDerating Curve



Resistance vs. Gate Source Voltage 300

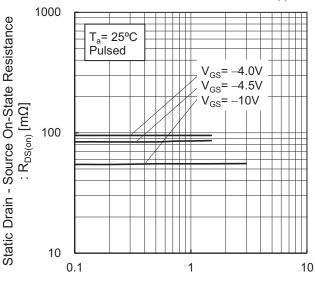
Fig.12 Static Drain - Source On - State



Junction Temperature : T_i [°C]

Gate - Source Voltage : -V_{GS} [V]

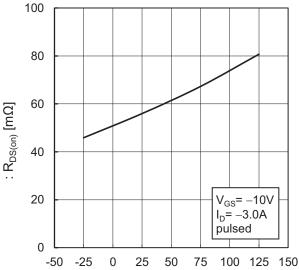
Fig.13 Static Drain - Source On - State Resistance vs. Drain Current(I)



Drain Current : -I_D [A]

Static Drain - Source On-State Resistance

Fig.14 Static Drain - Source On - State Resistance vs. Junction Temperature



Junction Temperature : T_i [°C]

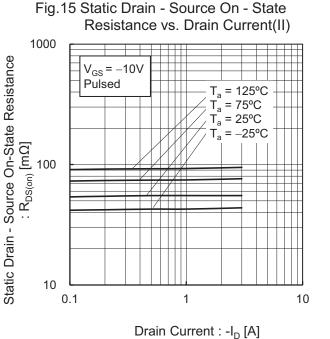


Fig.16 Static Drain - Source On - State Resistance vs. Drain Current(III)

1000

Pulsed

T_a = 125°C

T_a = 75°C

T_a = 25°C

T_a = -25°C

T_a = -25°C

Drain Current : -I_D [A]

Fig.17 Static Drain - Source On - State
Resistance vs. Drain Current(IV)

1000

V_{GS} = -4.0V

Pulsed

T_a = 125°C

T_a = 25°C

T_a = -25°C

T_a = -25°C

T_a = -25°C

Drain Current : -I_D [A]

0.01

0.1

•Electrical characteristic curves

Fig.18 Typical Capacitance vs. Drain - Source Voltage

1000 $C_{oss} C_{iss}$ C_{rss} $T_a = 25^{\circ}C_{f=1MHz}$ $V_{Gs} = 0V$

Drain - Source Voltage : -V_{DS} [V]

10

100

1

Fig.19 Switching Characteristics

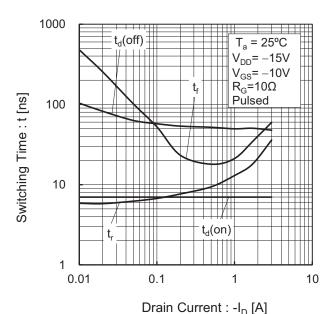
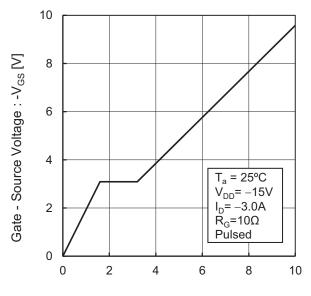
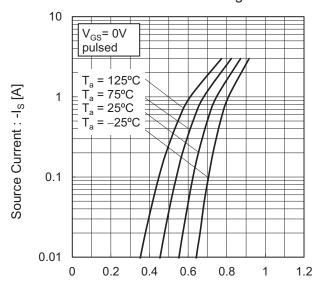


Fig.20 Dynamic Input Characteristics



Total Gate Charge : Q_g [nC]

Fig.21 Source Current vs. Source Drain Voltage



Source-Drain Voltage : -V_{SD} [V]

Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

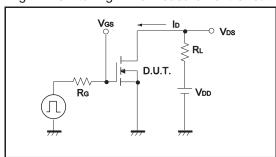


Fig.2-1 Gate Charge Measurement Circuit

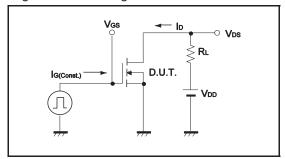


Fig.1-2 Switching Waveforms

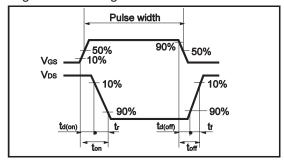
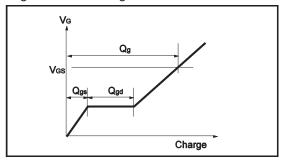
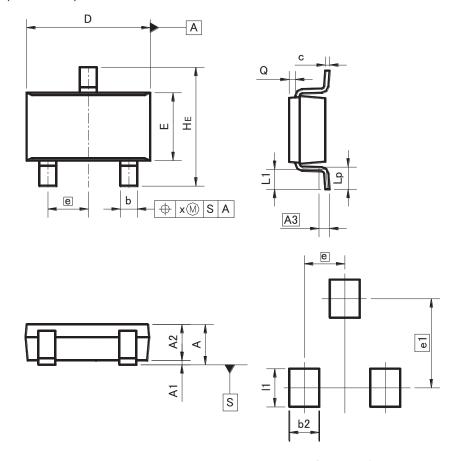


Fig.2-2 Gate Charge Waveform



●Dimensions (Unit : mm)

TSMT3



Patterm of terminal position areas

| DIM | MILIMI | ETERS | INC | HES |
|-----|--------|-------|-------|-------|
| DIM | MIN | MAX | MIN | MAX |
| Α | _ | 1.00 | - | 0.039 |
| A1 | 0.00 | 0.10 | 0 | 0.004 |
| A2 | 0.75 | 0.95 | 0.03 | 0.037 |
| A3 | 0.2 | 25 | 0.0 | 01 |
| b | 0.35 | 0.50 | 0.014 | 0.02 |
| С | 0.10 | 0.26 | 0.004 | 0.01 |
| D | 2.80 | 3.00 | 0.11 | 0.118 |
| E | 1.50 | 1.80 | 0.059 | 0.071 |
| е | 0.0 | 95 | 0.0 | 04 |
| HE | 2.60 | 3.00 | 0.102 | 0.118 |
| L1 | 0.30 | 0.60 | 0.012 | 0.024 |
| Lp | 0.40 | 0.70 | 0.016 | 0.028 |
| Q | 0.05 | 0.25 | 0.002 | 0.01 |
| х | _ | 0.20 | _ | 0.008 |

| DIM | MILIMI | ETERS | INC | HES | |
|-----|---------|-------|------|-------|--|
| DIM | MIN MAX | | MIN | MAX | |
| e1 | 2.10 | | 0.08 | | |
| b2 | | 0.70 | _ | 0.028 | |
| 11 | _ | 0.90 | - | 0.035 | |

Dimension in mm/inches

Notice

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|---------|---------|------------|--------|
| CLASSⅢ | OL ACOM | CLASS II b | ОГУООШ |
| CLASSIV | CLASSⅢ | CLASSⅢ | CLASSⅢ |

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 - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl₂, H₂S, NH₃, SO₂, and NO₂
 - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
 - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
 - If Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
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- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

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- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

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- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
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 - [b] the temperature or humidity exceeds those recommended by ROHM
 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
- Even under ROHM recommended storage condition, solderability of products out of recommended storage time period
 may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is
 exceeding the recommended storage time period.
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- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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Notice-PAA-E Rev.003



RRR030P03FRA - Web Page

| Part Number | RRR030P03FRA |
|-----------------------------|--------------|
| Package | TSMT3 |
| Unit Quantity | 3000 |
| Minimum Package Quantity | 3000 |
| Packing Type | Taping |
| Constitution Materials List | inquiry |
| RoHS | Yes |